

Vishay General Semiconductor

Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.39 \text{ V}$ at $I_F = 5 \text{ A}$



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 25 A				
V_{RRM}	100 V				
I _{FSM}	300 A				
E _{AS} at L = 100 mH	280 mJ				
V _F at I _F = 25 A	0.66 V				
T _J max.	150 °C				
Package	TO-3PW				
Diode variations	Dual common cathode				

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses

High efficiency operation

RoHS COMPLIANT HALOGEN

FREE

- Solder dip 275 °C max. 10 s, per JESD 22-B106
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

MECHANICAL DATA

Case: TO-3PW

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and

commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER		SYMBOL	V50100PW	UNIT		
Maximum repetitive peak reverse voltage		V_{RRM}	100	V		
Maximum average forward rectified current (fig. 1)	per device	I _{F(AV)}	50	А		
	per diode		25			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	300	А		
Non-repetitive avalanche energy at $T_J = 25$ °C, L = 100 m	E _{AS}	280	mJ			
Peak repetitive reverse current at t_p = 2 μ s, 1 kHz, T_J = 38 °C \pm 2 °C per diode				I _{RRM}	1.0	А
Voltage rate of change (rated V _R)	dV/dt	10 000	V/µs			
Operating junction and storage temperature range		T _J , T _{STG}	-40 to +150	°C		



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Breakdown voltage	I _R = 1.0 mA	T _A = 25 °C	V_{BR}	100 (minimum)	-	V	
Instantaneous forward voltage per diode	I _F = 5 A	- T _A = 25 °C	V _F ⁽¹⁾	0.48	-	V	
	I _F = 10 A			0.56	-		
	I _F = 20 A			0.69	-		
	I _F = 25 A			0.76	0.84		
	I _F = 5 A	- T _A = 125 °C		0.39	-		
	I _F = 10 A			0.50	-		
	I _F = 20 A			0.61	-		
	I _F = 25 A			0.66	0.74		
Reverse current per diode	V _R = 70 V	T _A = 25 °C	I _R ⁽²⁾	23	-	μA	
		T _A = 125 °C		11	-	mA	
	V _R = 100 V	T _A = 25 °C		-	1000	μA	
	v _R = 100 v	T _A = 125 °C		29	80	mA	

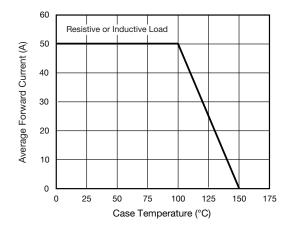
Notes

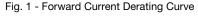
⁽²⁾ Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER		SYMBOL	V50100PW	UNIT		
Typical thermal resistance	per diode	- R _{θJC}	1.5	°C/W		
	per device		0.8	C/VV		

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-3PW	V50100PW-M3/4W	4.5	4W	30/tube	Tube		

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)





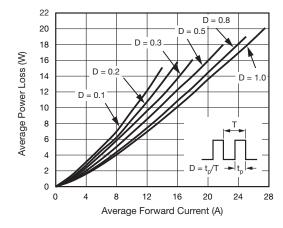


Fig. 2 - Forward Power Loss Characteristics Per Diode

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle



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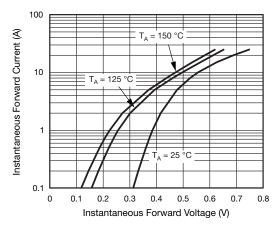


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

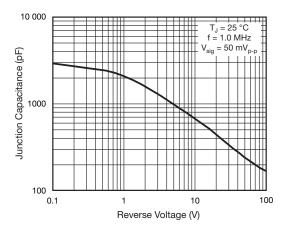


Fig. 5 - Typical Junction Capacitance Per Diode

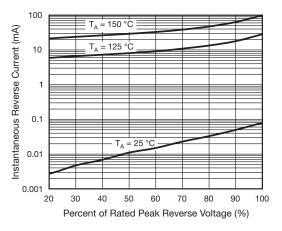


Fig. 4 - Typical Reverse Characteristics Per Diode

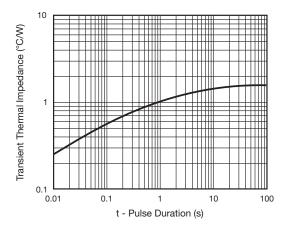
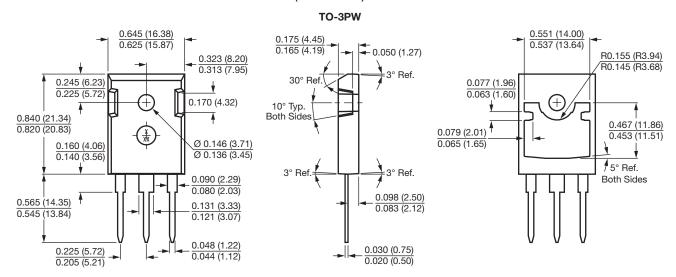


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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